

ABSTRACT OF THE DISCLOSURE

A solid-state imaging device includes at least one pixel section; and a control section for controlling an operation of the at least one pixel section. The at least one pixel section includes a light receiving section for outputting charges by performing photo-electric conversion of light incident thereon, and a transistor section having a charge accumulation region for accumulating the charges output by the light receiving section. The transistor section outputs an output signal representing a voltage value corresponding to an amount of charges accumulated in the charge accumulation region. The control section, for resetting the charges accumulated in the charge accumulation region after the output signal is output from the transistor section, injects the charges into the charge accumulation region before discharging the accumulated charges from the charge accumulation region.